Model 442

IR-EYETM INTEGRATED SENSOR Parallel Opposed Dual IR Detector With Integrated Signal Processing*



* Patent Pending. Manufactured under one or more of the following U.S. patents: 3,839,640 - 4,218,620 - 4,326,663 - 4,384,207 -4,437,003 - 4,441,023 - 4,523,095

The Model 442 IR-EYETM Integrated Sensor is a lithium tantalate pyroelectric parallel opposed dual element high gain detector with complete integral analog signal processing. This unit offers greatly improved detection capability over an extended temperature range of -40 to +70°C with no significant change in noise or sensitivity and significantly reduced temperature spiking.

Advantages

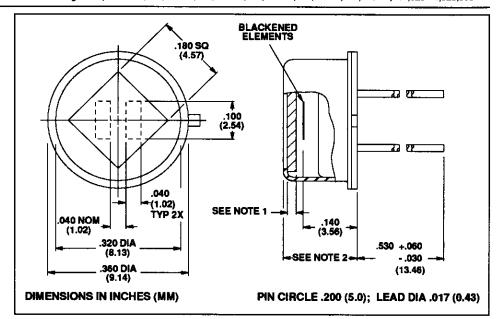
- · Eliminate Burn-In Tests
- Improve RF Immunity
- Eliminate False Alarms
- Simplify Circuitry
- Reduce Component Count
- · Improve Reliability

Features

- 100x Signal Amplification
- Stable, Accessable Internal Voltage Reference
- Wide Operating Temperature Range

Applications

- People / Object Detection
- Intrusion Detection
- Lighting Control
- Robotics
- Motion Sensing
- Automatic Door Control
- Safety Warning
- High Stability Industrial
 & Military Applications

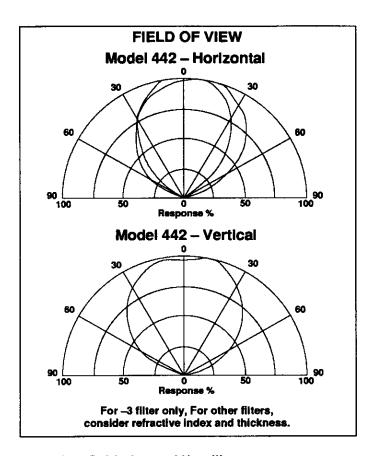


| Characteristics | | 442 | Unit | Test Conditions |
|--------------------------------|-----|-----------------------|------------------|---|
| Detector Type | Ī | Dual | | |
| Element Size | | 1.0 x 2.5 | mm, nominal (2x) | |
| D⁺ | | 2.2X10 ⁸ | cm√Hz/W | 1Hz BW |
| NEP | | 7.3X10 ⁻¹⁰ | W/√Hz | 1Hz BW |
| Responsivity | | 3.7X10 ⁵ | V/W | |
| Common Mode Rejection | nin | 5/1 | | • |
| t | ур | 15/1 | | |
| Noise | | 0.27 | mV√Hz | |
| Thermal Breakpoint ft t | yp | 0.15 | Hz | |
| Electrical Breakpoint fe t | ур | 5 | Hz | |
| Incident Power n | nax | 0.2 | W | |
| Power Supply Voltage | | 5-15 | VDC | |
| Power Supply Current n | nax | 2.2 | mÁ | |
| Output Voltage m | nax | V+ Rail-100 mV | ٧ | |
| Output Offset Voltage | | ± 500 | mV | |
| (Referenced to Pin 3) | | | | |
| Output Load r | nin | 10K | Ω | |
| Reference Voltage ¹ | | +2.500 ±80 mV | ν | See Note 1 |
| Storage Temperature | | -55 to +125 | °C | ΔT<50°C/minute |
| Operating Temperature | | -40 to +70 | °C | |

Characteristics are at 25°C, V+ = 5 VDC, f = 1Hz, 8 - 14 microns.

Data is established on a sample basis and is believed to be representative.

At a maximum load current of 100µA. See reverse for additional information.





These sensors have been improved over previous Models and can withstand normal handling and automatic assembly as well as wave soldering at 280°C for 10 seconds, at 1/4" (6.3mm) from the case bottom.

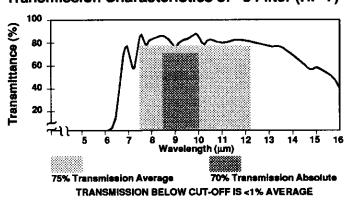
Contamination and fingerprints on the filter surface should be cleaned with alcohol and a soft cloth.

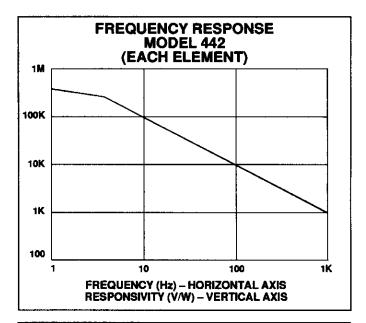
Avoid mechanical stresses on case and leads.

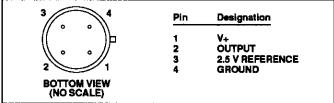
Static Discharge

Additional safety features are used internally to make these sensors almost immune to electrostatic discharge.

Transmission Characteristics of -3 Filter (HP-7)







Reference Voltage

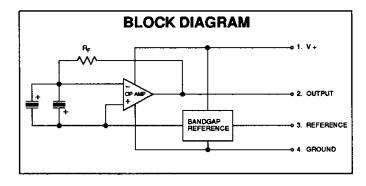
The internal reference voltage is accessible on pin 3. This voltage is used to bias the internal amplifier. Offset voltage is referred to this point.

This provides a low drift differential reference to allow for direct DC coupling of a subsequent comparator or A/D converter.

The recommended maximum load on this pin is 100µA (source only) to maintain electrical and thermal stability. Current loads greater than 100µA may adversely affect performance; however, the output is short circuit proof.

Light Leakage

Slight sensitivity to visible light leaking through the glass-to-metal seal on the base may be observed.





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